

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	3	"6338275"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2006/02/13 09:51
L2	68541	semiconduct\$4 near3 (film layer sheet pad).clm.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2006/02/13 09:51
L3	22354	2 and (metal\$4).clm.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2006/02/13 09:51
L4	1372	3 and (interface).clm.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2006/02/13 09:51
L5	240	4 and (strain stress load pressure force).clm.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2006/02/13 09:52
L6	1	5 and (shunt\$4).clm.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2006/02/13 09:52
L7	8	5 and (shunt\$4)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2006/02/13 09:54
L8	132	5 and (resistance)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2006/02/13 09:54